





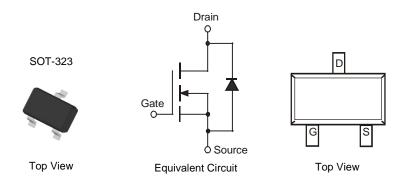
N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 6. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.006 grams (approximate)



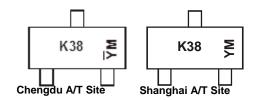
Ordering Information (Note 4)

Part Number	Case	Packaging
BSS138W -7-F	SOT-323	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



 $\begin{array}{l} K38 = Product\ Type\ Marking\ Code \\ YM = Date\ Code\ Marking\ for\ SAT\ (Shanghai\ Assembly/\ Test\ site) \\ \overline{Y}M = Date\ Code\ Marking\ for\ CAT\ (Chengdu\ Assembly/\ Test\ site) \\ Y\ or\ \overline{Y} = Year\ (ex:\ A=2013) \\ M = Month\ (ex:\ 9=September) \end{array}$

Date Code Key

Year	201	2	2013		2014	20	15	2016		2017	1	2018
Code	Z		Α		В	(D		Е		F
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Drain-Source Voltage		V _{DSS}	50	V
Drain-Gate Voltage (Note 5)		V_{DGR}	50	V
Gate-Source Voltage	Continuous	V _{GSS}	±20	V
Drain Current (Note 6)	Continuous	I _D	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 6)	P_{D}	200	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	625	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	50	75	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}			0.5	μΑ	$V_{DS} = 50V$, $V_{GS} = 0V$	
Gate-Body Leakage	I _{GSS}			±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)				a		_	
Gate Threshold Voltage	V _{GS(th)}	0.5	1.2	1.5	>	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	R _{DS (ON)}		1.4	3.5	Ω	$V_{GS} = 10V, I_D = 0.22A$	
Forward Transconductance	g _{FS}	100			mS	$V_{DS} = 25V$, $I_D = 0.2A$, $f = 1.0KHz$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	_	50	pF		
Output Capacitance	Coss			25	рF	$V_{DS} = 10V, V_{GS} = 0V, f = 1.0MHz$	
Reverse Transfer Capacitance	C _{rss}			8.0	pF	1	
SWITCHING CHARACTERISTICS(Note 8)							
Turn-On Delay Time	t _{D(ON)}			20	ns	$V_{DD} = 30V, I_D = 0.2A,$	
Turn-Off Delay Time	t _{D(OFF)}	_	_	20	ns	$R_{GEN} = 50\Omega$	

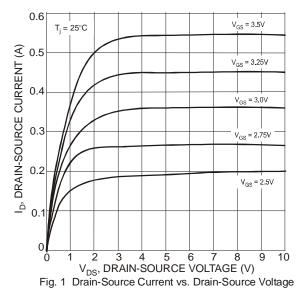
Notes: 5. $R_{GS} \le 20 K\Omega$.

6. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com.

^{7.} Short duration pulse test used to minimize self-heating effect.

^{8.} Guaranteed by design. Not subject to production testing.







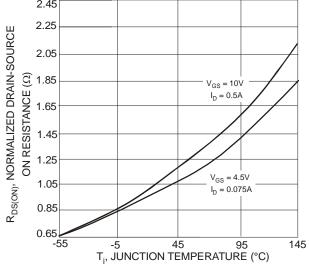


Fig. 3 Drain-Source On Resistance vs. Junction Temperature

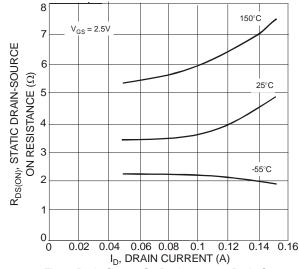
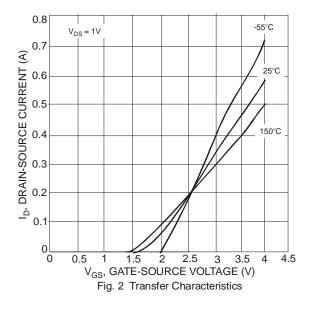


Fig. 5 Drain-Source On Resistance vs. Drain Current



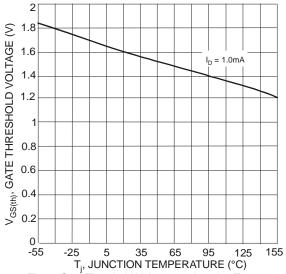


Fig. 4 Gate Threshold Voltage vs. Junction Temperature

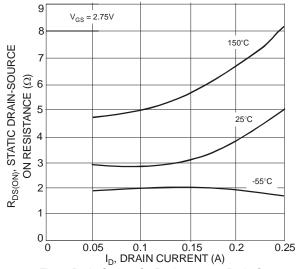
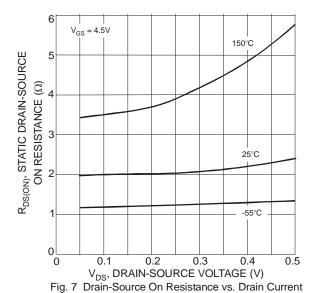
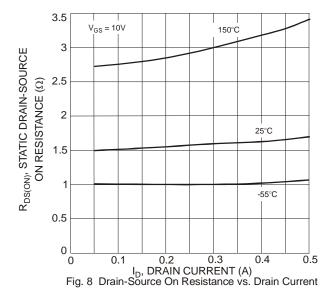
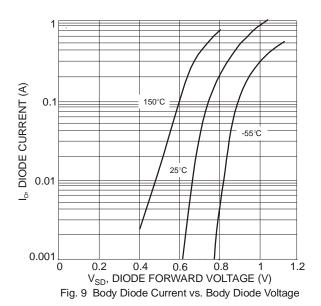


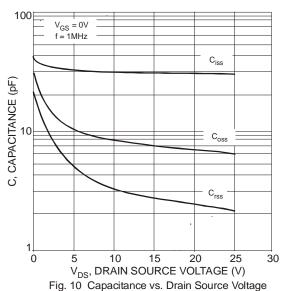
Fig. 6 Drain-Source On Resistance vs. Drain Current



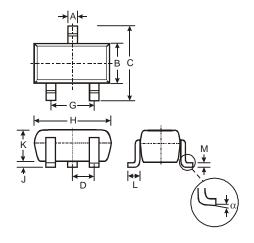








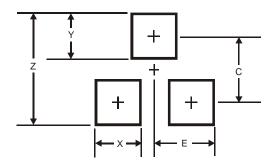
Package Outline Dimensions



SOT-323							
Dim	Min	Max	Тур				
Α	0.25	0.40	0.30				
В	1.15	1.35	1.30				
С	2.00	2.20	2.10				
D	-	-	0.65				
G	1.20	1.40	1.30				
Н	1.80	2.20	2.15				
J	0.0	0.10	0.05				
K	0.90	1.00	0.95				
L	0.25	0.40	0.30				
M	0.10	0.18	0.11				
α	0°	8°	-				
All	All Dimensions in mm						



Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Υ	0.9
С	1.9
E	1.0

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